





ZXMN3A01Z

30V N-CHANNEL ENHANCEMENT MODE MOSFET IN SOT89 PACKAGE

Product Summary

V _{(BR)DSS}	R _{DS(on)} Max	I _D max T _A = 25°C (Note 5)		
30V	120mΩ @ V _{GS} = 10V	3.3A		
307	180mΩ @ V _{GS} = 4.5V	2.7A		

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- · Power Management functions
- Motor control

Features and Benefits

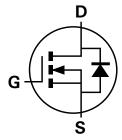
- Low On-Resistance
- Low Threshold
- Fast Switching Speed
- Low Gate Drive
- Lead Free/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

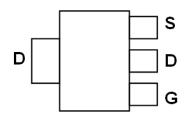
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (approximate)







Device symbol



Pin-out Top

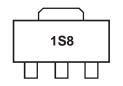
Ordering Information (Note 3)

-					
	Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	ZXMN3A01ZTA	1S8	7	12	1,000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com

Marking Information



1S8 = Product type Marking Code



ZXMN3A01Z

Maximum Ratings @TA = 25°C unless otherwise specified

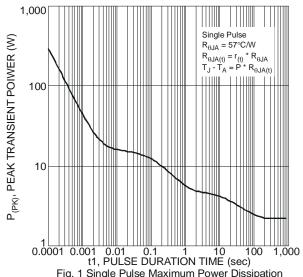
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current	Steady State	@ V _{GS} = 10V; T _A = 25°C (Note 5) @ V _{GS} = 10V; T _A = 75°C (Note 5) @ V _{GS} = 10V; T _A = 75°C (Note 4)	I _D	3.3 2.7 2.2	А
Pulsed Drain Current (Note 6)			I _{DM}	20	Α
Continuous Source Current (Body Diode) (Note 5)			IS	3.3	Α
Pulsed Source Current (Body Diode) (Note 6)			I _{SM}	20	Α

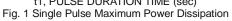
Thermal Characteristics @TA = 25°C unless otherwise specified

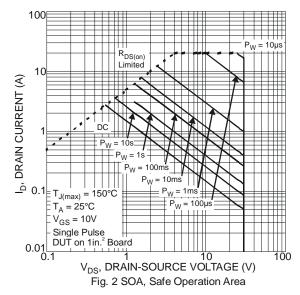
Characteristic		Symbol	Value	Unit
Dower Dissipation	(Note 4)	0	0.97	W
Power Dissipation	(Note 5)	P _D	2.12	W
The amount Desistance I have time to Ameliant	(Note 4)	Б	129	°C/W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	59	°C/W
Operating and Storage Temperature Range		T_{J}, T_{STG}	-55 to +150	°C

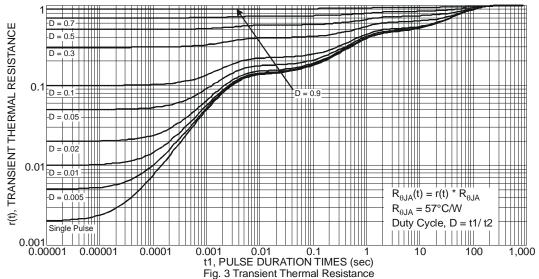
Notes:

- 4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout
- 5. Device mounted on 25mm X 25mm FR-4 substrate PC board with 2oz copper
- 6. Single pulse rating 25mm x 25mm FR4 PCB, D=0.02, pulse width 300us pulse width limited by maximum junction temperature.









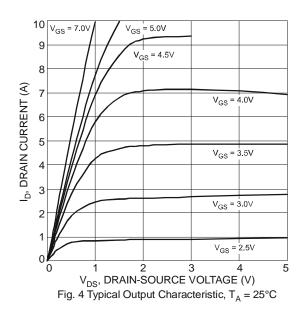


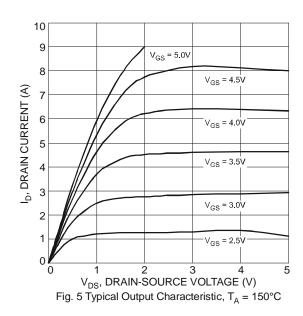
Electrical Characteristics $@T_A = 25$ °C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	0.5	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	1	-	1	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance (Note 7)	D		0.106	120	mΩ	$V_{GS} = 10V, I_D = 2.5A$	
Static Drain-Source Off-Resistance (Note 1)	R _{DS} (ON)	-	-	180	m \(\frac{1}{2}\)	$V_{GS} = 4.5V, I_D = 2A$	
Forward Transconductance (Note 7 & 9)	g fs	-	3.5	-	S	$V_{DS} = 4.5V, I_{D} = 2.5A$	
Diodes Forward Voltage (Note 7)	V_{SD}	-	0.85	0.95	V	$T_J = 25^{\circ}C$, $I_S = 1.7A$, $V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 8 & 9)	C _{iss}	-	186	-	pF), osy, y	
Output Capacitance (Note 8 & 9)	Coss	-	48	-	pF	$V_{DS} = 25V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance (Note 8 & 9)	C _{rss}	-	29	-	pF	1 = 1.001112	
Gate Charge (Note 8 & 9)	Qg	-	2.6	-	nC	$V_{GS} = 4.5V$, $V_{DS} = 15V$, $I_D = 2.5A$	
Total Gate Charge (Note 8 & 9)	Qg	-	5.0	-	nC	10)/)/ 45)/	
Gate-Source Charge (Note 8 & 9)	Q _{gs}	-	8.0	-	nC	$V_{GS} = 10V, V_{DS} = 15V,$	
Gate-Drain Charge (Note 8 & 9)	Q_{gd}	-	1.2	-	nC	$I_D = 2.5A$	
Reverse Recovery Time (Note 9)	t _{rr}		17.7		ns	$T_J = 25^{\circ}C$, $I_S = 2.5A$,	
Reverse Recovery Charge (Note 9)	Q _{rr}		13.0		nC	di/dt = 100A/μs	
Turn-On Delay Time (Note 8 & 9)	t _{D(on)}	-	2.6	-	ns		
Turn-On Rise Time (Note 8 & 9)	tr	-	4.1	-	ns	$V_{GS} = 10V, V_{DD} = 15V,$	
Turn-Off Delay Time (Note 8 & 9)	t _{D(off)}	-	13.5	-	ns	$R_G = 6\Omega$, $I_D = 2.5A$	
Turn-Off Fall Time (Note 8 & 9)	t _f	-	3.6	-	ns		

Notes:

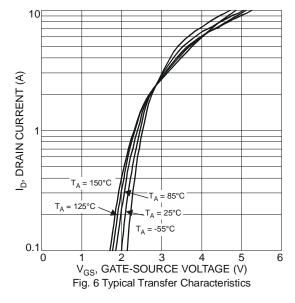
- 7. Measured under pulsed conditions. Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$. 8. Switching characteristics are independent of operating junction temperature. 9. For design aid only, not subject to production testing.

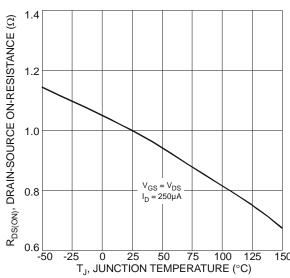


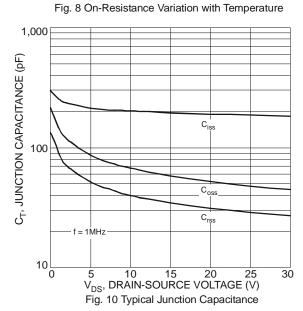


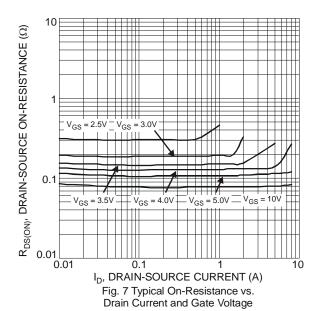


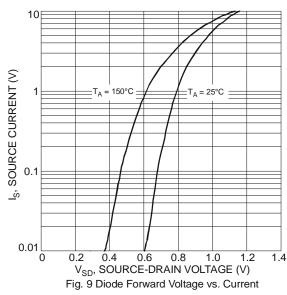
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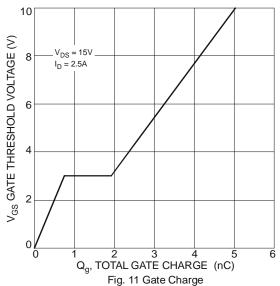






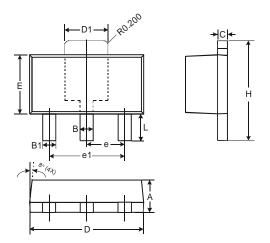






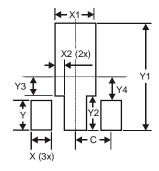


Package Outline Dimensions



SOT89					
Dim	Min	Max			
Α	1.40	1.60			
В	0.44	0.62			
B1	0.35	0.54			
С	0.35	0.43			
D	4.40	4.60			
D1	1.52	1.83			
Е	2.29	2.60			
е	1.50 Typ				
e1	3.00 Typ				
Н	3.94	4.25			
L	0.89	1.20			
All [All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1 500





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